### **Product Preview**

# Quasi-Resonant Primary Side Current-Mode Controller for LED Lighting

The NCL30080 is a PWM current mode controller targeting isolated flyback and non-isolated constant current topologies. The controller operates in a quasi-resonant mode to provide high efficiency. Thanks to a novel control method, the device is able to precisely regulate a constant LED current from the primary side. This removes the need for secondary side feedback circuitry, biasing and an optocoupler.

The device is highly integrated with a minimum number of external components. A wide  $V_{CC}$  range simplifies the design process and allows a single design to support a wide LED forward voltage range. A robust suite of safety protection is built in to simplify the design. This device is specifically intended for very compact space efficient designs

#### **Features**

- Quasi-resonant Peak Current-mode Control Operation
- Primary Side Sensing (no optocoupler needed)
- Wide V<sub>CC</sub> Range
- Precise LED Constant Current Regulation ±1% Typical
- Line Feed-forward for Enhanced Regulation Accuracy
- Low LED Current Ripple
- 250 mV ±2% Guaranteed Voltage Reference for Current Regulation
- ~ 0.9 Power Factor with Valley Fill Input Stage
- Low LED Current Ripple
- Source 300 mA / Sink 500 mA Totem Pole Driver with 12 V Gate Clamp
- Low Start-up Current (13 µA typ.)
- Small Space Saving Low Profile Package
- Wide Temperature Range of -40 to +125°C
- Pb-free, Halide-free MSL1 Product
- Robust Protection Features
  - Over Voltage / LED Open Circuit Protection
  - Secondary Diode Short Protection
  - Output Short Circuit Protection
  - Shorted Current Sense Pin Fault Detection
  - Latched and Auto-recoverable Versions
  - ♦ Brown-out
  - V<sub>CC</sub> Under Voltage Lockout
  - ◆ Thermal Shutdown

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TSOP-6 SN SUFFIX CASE 318G

#### **MARKING DIAGRAM**



AAx = Specific Device Code

x = E or F

A = Assembly Location

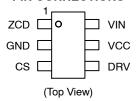
Y = Year

W = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

#### **PIN CONNECTIONS**



#### **Typical Applications**

- Integral LED Bulbs
- LED Power Driver Supplies
- LED Light Engines

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 21 of this data sheet.

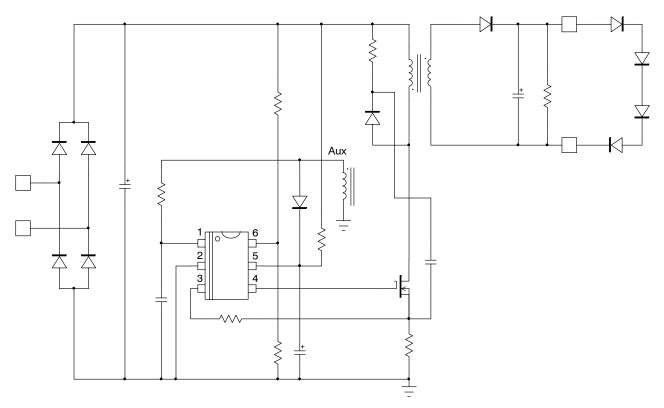


Figure 1. Typical Application Schematic for NCL30080

**Table 1. PIN FUNCTION DESCRIPTION** 

Pin No	Pin Name	Function	Pin Description	
1	ZCD	Zero Crossing Detection	Connected to the auxiliary winding; this pin detects the core reset event.	
2	GND	-	The controller ground	
3	CS	Current sense	This pin monitors the primary peak current	
4	DRV	Driver output	The current capability of the totem pole gate drive (+0.3/–0.5 A) makes it suitable to effectively drive a broad range of power MOSFETs.	
5	VCC	Supplies the controller	This pin is connected to an external auxiliary voltage.	
6	VIN	Input voltage sensing Brown-Out	This pin observes the HV rail and is used in valley selection. This pin also monitors and protects for low mains conditions.	

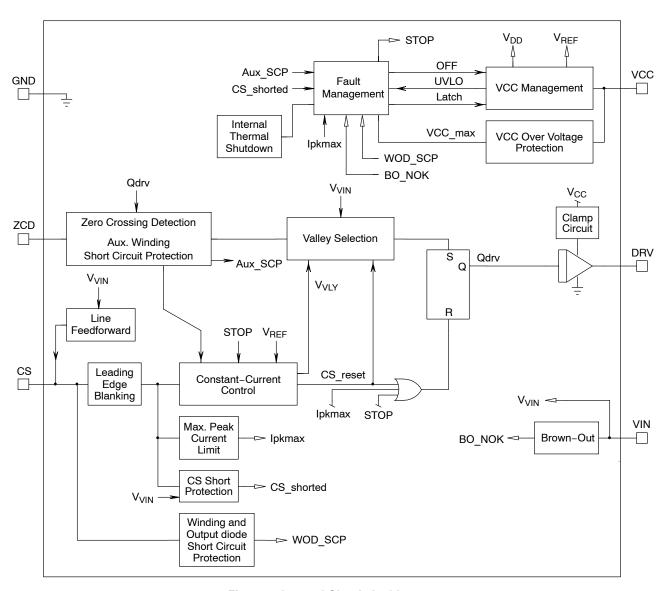


Figure 2. Internal Circuit Architecture

**Table 2. MAXIMUM RATINGS TABLE** 

Symbol	Rating	Value	Unit
V <sub>CC(MAX)</sub>	Maximum Power Supply voltage, VCC pin, continuous voltage  Maximum current for VCC pin	-0.3, +35 Internally limited	V mA
V <sub>DRV(MAX)</sub> I <sub>DRV(MAX)</sub>	Maximum driver pin voltage, DRV pin, continuous voltage  Maximum current for DRV pin	-0.3, V <sub>DRV</sub> (Note 1) -500, +800	V mA
V <sub>MAX</sub> I <sub>MAX</sub>	Maximum voltage on low power pins (except pins DRV and VCC) Current range for low power pins (except pins ZCD, DRV and VCC)	0.3, +5.5 -2, +5	V mA
V <sub>ZCD(MAX)</sub> I <sub>ZCD(MAX)</sub>	Maximum voltage for ZCD pin  Maximum current for ZCD pin	-0.3, +10 -2, +5	V mA
$R_{\theta J-A}$	Thermal Resistance, Junction-to-Air	360	°C/W
T <sub>J(MAX)</sub>	Maximum Junction Temperature	150	°C
	Operating Temperature Range	-40 to +125	°C
	Storage Temperature Range	-60 to +150	°C
	ESD Capability, HBM model (Note 2)	4	kV
	ESD Capability, MM model (Note 2)	200	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V<sub>DRV</sub> is the DRV clamp voltage V<sub>DRV(high)</sub> when V<sub>CC</sub> is higher than V<sub>DRV(high)</sub>. V<sub>DRV</sub> is V<sub>CC</sub> unless otherwise noted.

2. This device series contains ESD protection and exceeds the following tests: Human Body Model 4000 V per Mil–Std–883, Method 3015.

3. This device contains latch–up protection and exceeds 100 mA per JEDEC Standard JESD78 except for VIN pin which passes 60 mA.

 $\textbf{Table 3. ELECTRICAL CHARACTERISTICS} \text{ (Unless otherwise noted: For typical values } T_J = 25^{\circ}\text{C}, \ V_{CC} = 12 \text{ V}; \\ \text{For min/max values } T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}, \ \text{Max } T_J = 150^{\circ}\text{C}, \ V_{CC} = 12 \text{ V})$ 

Description	Test Condition	Symbol	Min	Тур	Max	Unit
STARTUP AND SUPPLY CIRCUITS	1					
Supply Voltage						V
Startup Threshold	V <sub>CC</sub> increasing	$V_{CC(on)}$	16	18	20	
Minimum Operating Voltage	V <sub>CC</sub> decreasing	V <sub>CC(off)</sub>	8.2	8.8	9.4	
Hysteresis V <sub>CC(on)</sub> – V <sub>CC(off)</sub>	V <sub>CC</sub> decreasing	V <sub>CC(HYS)</sub>	8	_	-	
Internal logic reset		V <sub>CC(reset)</sub>	3.5	4.5	5.5	
Over Voltage Protection VCC OVP threshold		V <sub>CC(OVP)</sub>	26	28	30	V
V <sub>CC(off)</sub> noise filter		t <sub>VCC(off)</sub>	_	5	=	μS
V <sub>CC(reset)</sub> noise filter-		t <sub>VCC(reset)</sub>	_	20	_	
Startup current		I <sub>CC(start)</sub>	-	13	30	μΑ
Startup current in fault mode		I <sub>CC(sFault)</sub>	_	46	60	μΑ
Supply Current						mA
Device Disabled/Fault	$V_{CC} > V_{CC(off)}$	I <sub>CC1</sub>	0.8	1.0	1.4	
Device Enabled/No output load on pin 4	$F_{sw} = 65 \text{ kHz}'$	I <sub>CC2</sub>	_	2.15	4.0	
Device Switching (F <sub>sw</sub> = 65 kHz)	$C_{DRV} = 470 pF,$	I <sub>CC3</sub>	_	2.6	5.0	
	F <sub>sw</sub> = 65 kHz					
CURRENT SENSE	_		1	,	•	
Maximum Internal current limit		$V_{ILIM}$	0.95	1	1.05	V
Leading Edge Blanking Duration for $V_{ILIM}$ ( $T_j = -25^{\circ}\text{C}$ to 125°C)		t <sub>LEB</sub>	250	300	350	ns
Leading Edge Blanking Duration for $V_{ILIM}$ ( $T_j = -40^{\circ}\text{C}$ to 125°C)		t <sub>LEB</sub>	240	300	350	ns
Input Bias Current	DRV high	I <sub>bias</sub>	-	0.02	-	μΑ
Propagation delay from current detection to gate off-state		t <sub>ILIM</sub>	-	50	150	ns
Threshold for immediate fault protection activation		V <sub>CS(stop)</sub>	1.35	1.5	1.65	V
Leading Edge Blanking Duration for V <sub>CS(stop)</sub>		t <sub>BCS</sub>	-	120	_	ns
Blanking time for CS to GND short detection $V_{pinVIN} = 1 \text{ V}$		t <sub>CS(blank1)</sub>	6	-	12	μs
Blanking time for CS to GND short detection $V_{pinVIN} = 3.3 \text{ V}$		t <sub>CS(blank2)</sub>	2	-	4	μs
GATE DRIVE				•	•	•
Drive Resistance						Ω
DRV Sink		R <sub>SNK</sub>	_	13	_	
DRV Source		R <sub>SRC</sub>	_	30	_	
Drive current capability						mA
DRV Sink (Note 4)		I <sub>SNK</sub>	_	500	_	
DRV Source (Note 4)		I <sub>SRC</sub>	_	300	_	
Rise Time (10% to 90%)	C <sub>DRV</sub> = 470 pF	t <sub>r</sub>	_	40	_	ns
Fall Time (90% to 10%)	C <sub>DRV</sub> = 470 pF	t <sub>f</sub>		30		ns
DRV minimum high level	$V_{CC} = V_{CC(off)} + 0.2 \text{ V}$ $C_{DRV} = 470 \text{ pF},$ $R_{DRV} = 33 \text{ k}\Omega$	V <sub>DRV(low)</sub>	8	_	-	V
DRV high clamp level	$V_{CC}$ = 30 V $C_{DRV}$ = 470 pF, $R_{DRV}$ = 33 k $\Omega$	$V_{DRV(high)}$	10	12	14	٧

4. Guaranteed by design

 $\textbf{Table 3. ELECTRICAL CHARACTERISTICS} \text{ (Unless otherwise noted: For typical values } T_J = 25^{\circ}\text{C}, \ V_{CC} = 12 \text{ V}; \\ \text{For min/max values } T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}, \ \text{Max } T_J = 150^{\circ}\text{C}, \ V_{CC} = 12 \text{ V})$ 

Description	Test Condition	Symbol	Min	Тур	Max	Unit
ZERO VOLTAGE DETECTION CIRCUIT						
ZCD threshold voltage	V <sub>ZCD</sub> increasing	V <sub>ZCD(THI)</sub>	25	45	65	mV
ZCD threshold voltage (Note 4)	V <sub>ZCD</sub> decreasing	V <sub>ZCD(THD)</sub>	5	25	45	mV
ZCD hysteresis (Note 4)		V <sub>ZCD(HYS)</sub>	10	_	-	mV
Threshold voltage for output short circuit or aux. winding short circuit detection		V <sub>ZCD(short)</sub>	0.8	1	1.2	V
Short circuit detection Timer	V <sub>ZCD</sub> < V <sub>ZCD(short)</sub>	t <sub>OVLD</sub>	70	90	110	ms
Auto-recovery timer duration		t <sub>recovery</sub>	3	4	5	S
Input clamp voltage High state Low state	I <sub>pin1</sub> = 3.0 mA I <sub>pin1</sub> = -2.0 mA	V <sub>CH</sub> V <sub>CL</sub>	_ _0.9	9.5 -0.6	_ -0.3	V
Propagation Delay from valley detection to DRV high	V <sub>ZCD</sub> decreasing	t <sub>DEM</sub>	_	_	150	ns
Equivalent time constant for ZCD input (Note 4)		t <sub>PAR</sub>	_	20	_	ns
Blanking delay after on-time		t <sub>BLANK</sub>	2.25	3	3.75	μs
Timeout after last demag transition		t <sub>TIMO</sub>	5	6.5	8	μs
CONSTANT CURRENT CONTROL						
Reference Voltage at T <sub>j</sub> = 25°C		V <sub>REF</sub>	245	250	255	mV
Reference Voltage $T_j = -40^{\circ}C$ to 125°C		V <sub>REF</sub>	242.5	250	257.5	mV
Current sense lower threshold for detection of the leakage inductance reset time		V <sub>CS(low)</sub>	30	55	80	mV
LINE FEED-FORWARD						
V <sub>VIN</sub> to I <sub>CS(offset)</sub> conversion ratio		K <sub>LFF</sub>	15	17	19	μ <b>A</b> /V
Offset current maximum value	V <sub>pinVIN</sub> = 4.5 V	I <sub>offset(MAX)</sub>	67.5	76.5	85.5	μΑ
VALLEY SELECTION						
Threshold for line range detection $V_{in}$ increasing (1 <sup>st</sup> to 2 <sup>nd</sup> valley transition for $V_{REF} > 0.75 \text{ V}$ )	V <sub>VIN</sub> increasing	$V_{HL}$	2.28	2.4	2.52	V
Threshold for line range detection $V_{in}$ decreasing (2 <sup>nd</sup> to 1 <sup>st</sup> valley transition for $V_{REF} > 0.75 \text{ V}$ )	V <sub>VIN</sub> decreasing	$V_{LL}$	2.18	2.3	2.42	٧
Blanking time for line range detection		t <sub>HL(blank)</sub>	15	25	35	ms
THERMAL SHUTDOWN						
Thermal Shutdown (Note 4)	Device switching (F <sub>SW</sub> around 65 kHz)	T <sub>SHDN</sub>	130	155	170	°C
Thermal Shutdown Hysteresis (Note 4)		T <sub>SHDN(HYS)</sub>	_	55	-	°C
BROWN-OUT	•		•	•	•	•
Brown-Out ON level (IC start pulsing)	V <sub>SD</sub> increasing	V <sub>BO(on)</sub>	0.90	1	1.10	V
Brown-Out OFF level (IC shuts down)	V <sub>SD</sub> decreasing	V <sub>BO(off)</sub>	0.85	0.9	0.95	٧
BO comparators delay		t <sub>BO(delay)</sub>	_	30	_	μs
Brown-Out blanking time		t <sub>BO(blank)</sub>	35	50	65	ms
Brown-Out pin bias current		I <sub>BO(bias)</sub>	-250	_	250	nA

<sup>4.</sup> Guaranteed by design

#### **Application Information**

The NCL30080 implements a current-mode architecture operating in quasi-resonant mode. Thanks to proprietary circuitry, the controller is able to accurately regulate the secondary side current of the flyback converter without using any opto-coupler or measuring directly the secondary side current.

- Quasi-Resonance Current-Mode Operation:
   implementing quasi-resonance operation in peak
   current-mode control, the NCL30080 optimizes the
   efficiency by switching in the valley of the MOSFET
   drain-source voltage. Thanks to a smart control
   algorithm, the controller locks-out in a selected valley
   and remains locked until the input voltage or the output
   current set point significantly changes.
- Primary Side Constant Current Control: thanks to a
  proprietary circuit, the controller is able to compensate
  for the leakage inductance of the transformer and allow
  accurate control of the secondary side current.
- Line Feed-forward: compensation for possible variation of the output current caused by system slew rate variation.
- Open LED protection: if the voltage on the VCC pin exceeds an internal limit, the controller shuts down and waits 4 seconds before restarting switching.

- Brown-Out: the controller includes a brown-out circuit with a validation timer which safely stops the controller in the event that the input voltage is too low.
   The device will automatically restart if the line recovers.
- Cycle-by-cycle peak current limit: when the current sense voltage exceeds the internal threshold V<sub>ILIM</sub>, the MOSFET is turned off for the rest of the switching cycle.
- Winding Short-Circuit Protection: an additional comparator with a short LEB filter (t<sub>BCS</sub>) senses the CS signal and stops the controller if V<sub>CS</sub> reaches 1.5 x V<sub>ILIM</sub>. For noise immunity reasons, this comparator is enabled only during the main LEB duration t<sub>LEB</sub>.
- Output Short-circuit protection: If a very low voltage is applied on ZCD pin for 90 ms (nominal), the controllers assume that the output or the ZCD pin is shorted to ground and enters shutdown. The autorestart version (B suffix) waits 4 seconds, then the controller restarts switching. In the latched version (A suffix), the controller is latched as long as V<sub>CC</sub> stays above the V<sub>CC(reset)</sub> threshold.

### **Constant Current Control**

Figure 3 shows the basic circuit of a flyback converter. Figure 4 portrays the primary and secondary current of a flyback converter operating in discontinuous conduction mode (DCM).

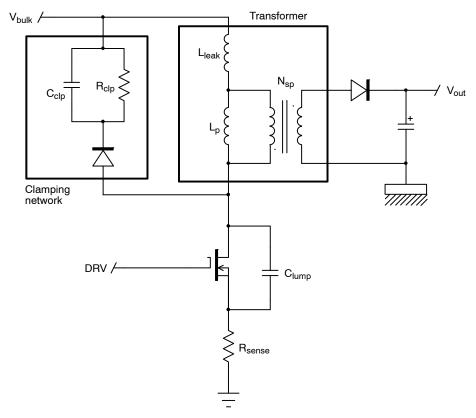


Figure 3. Basic Flyback Converter Schematic

During the on-time of the MOSFET, the bulk voltage  $V_{bulk}$  is applied to the magnetizing and leakage inductors  $L_p$  and  $L_{leak}$  and the current ramps up.

When the MOSFET is turned-off, the inductor current first charges  $C_{lump}$ . The output diode is off until the voltage across  $L_{p}$  reverses and reaches:

$$N_{sp}(V_{out} + V_f)$$
 (eq. 1)

The output diode current increase is limited by the leakage inductor. As a result, the secondary peak current is reduced:

$$I_{D,pk} < \frac{I_{L,pk}}{N_{sp}}$$
 (eq. 2)

The diode current reaches its peak when the leakage inductor is reset. Thus, in order to accurately regulate the output current, we need to take into account the leakage inductor current. This is accomplished by sensing the clamping network current. Practically, a node of the clamp capacitor is connected to  $R_{\text{sense}}$  instead of the bulk voltage  $V_{\text{bulk}}$ . Then, by monitoring the voltage on the CS pin, we have an image of the primary current (red curve in Figure 4).

When the diode conducts, the secondary current decreases linearly from  $I_{D,Dk}$  to zero. When the diode current has

turned off, the drain voltage begins to oscillate because of the resonating network formed by the inductors ( $L_p + L_{leak}$ ) and the lump capacitor. This voltage is reflected on the auxiliary winding wired in flyback mode. Thus, by monitoring the auxiliary winding voltage, we can detect the end of the conduction time of secondary diode. The constant current control block picks up the leakage inductor current, the end of conduction of the output rectifier and controls the drain current to maintain the output current constant.

We have:

$$I_{out} = \frac{V_{REF}}{2N_{sp}R_{sense}}$$
 (eq. 3)

The output current value is set by choosing the sense resistor:

$$R_{\text{sense}} = \frac{V_{\text{ref}}}{2N_{\text{sp}}I_{\text{out}}}$$
 (eq. 4)

From Equation 3, the first key point is that the output current is independent of the inductor value. Moreover, the leakage inductance does not influence the output current value as the reset time is processed by the controller.

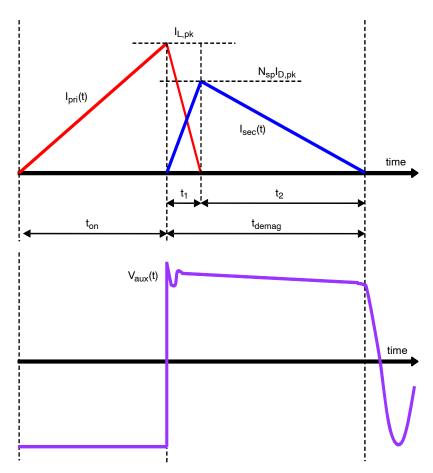


Figure 4. Flyback Currents and Auxiliary Winding Voltage in DCM

#### Internal Soft-Start

At startup or after recovering from a fault, there is a small internal soft–start of 40  $\mu$ s.

In addition, during startup, as the output voltage is zero volts, the demagnetization time is long and the constant

current control block will slowly increase the peak current towards its nominal value as the output voltage grows. Figure 5 shows a soft-start simulation example for a 9 W LED driver illustrating a natural soft startup.

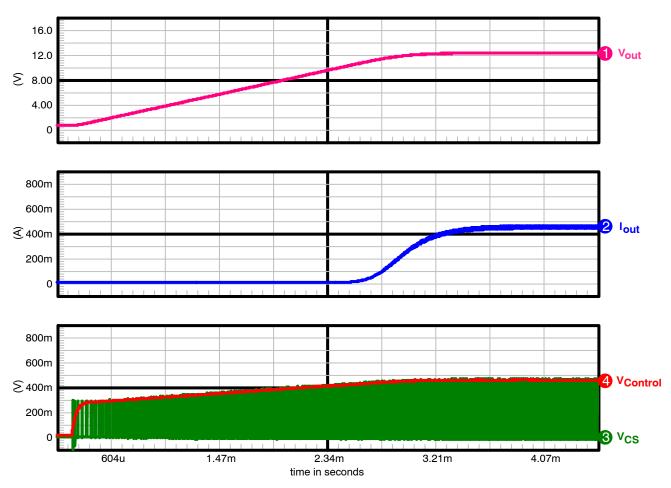


Figure 5. Startup Simulation Showing the Natural Soft-start

#### Cycle-by-Cycle Current Limit

When the current sense voltage exceeds the internal threshold  $V_{\rm ILIM}$ , the MOSFET is turned off for the rest of the switching cycle (Figure 6).

#### Winding and Output Diode Short-Circuit Protection

In parallel with the cycle-by-cycle sensing of the CS pin, another comparator with a reduced LEB ( $t_{BCS}$ ) and a higher threshold (1.5 V typical) is integrated to sense a winding short-circuit and immediately stops the DRV pulses. The controller goes into auto-recovery mode in version B.

In version A, the controller is latched. In latch mode, the DRV pulses stop and VCC ramps up and down. The circuit un–latches when VCC pin voltage drops below  $V_{CC(reset)}$  threshold.

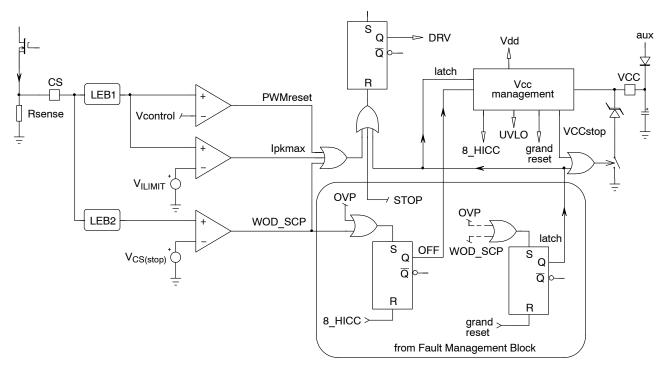


Figure 6. Winding Short Circuit Protection, Max. Peak Current Limit Circuits

### **V<sub>CC</sub>** Over Voltage Protection (Open LED Protection)

If no output load is connected to the LED string fails open circuited, the controller must be able to safely limit the output voltage excursion.

In the NCL30080, when the  $V_{CC}$  voltage reaches the  $V_{CC(OVP)}$  threshold, the controller stops the DRV pulses and the 4–s timer starts counting. The IC re–start switching after the 4–s timer has elapsed as long as  $V_{CC} \ge V_{CC(on)}$ . This is illustrated in Figure 7.

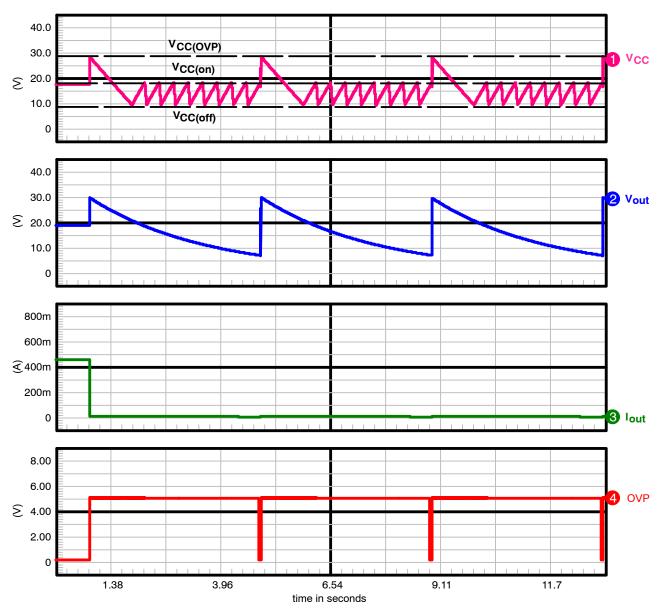


Figure 7. Open LED Protection Chronograms

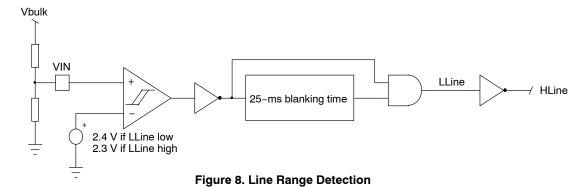
#### **Valley Lockout**

Quasi-square wave resonant systems have a wide switching frequency excursion. The switching frequency increases when the output load decreases or when the input voltage increases. The switching frequency of such systems must be limited.

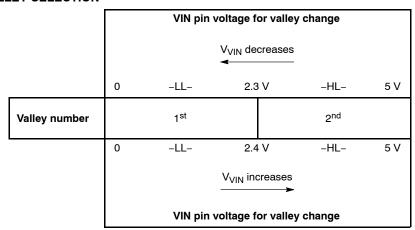
The NCL30080 changes the valley as the input voltage increases. This limits the switching frequency excursion. Once a valley is selected, the controller stays locked in the

valley until the input voltage varies significantly. This avoids valley jumping and the inherent noise caused by this phenomenon.

The input voltage is sensed by the VIN pin. The internal logic selects the operating valley according to VIN pin voltage (line range detection in Figure 8). For a universal mains design, the controller operates in the first valley at low line and in the second valley at high line.



**Table 4. VALLEY SELECTION** 



#### **Zero Crossing Detection Block**

The ZCD pin detects when the drain-source voltage of the power MOSFET reaches a valley.

A valley is detected when the voltage on pin 1 crosses below the  $V_{ZCD(THD)}$  internal threshold.

At startup or in case of extremely damped free oscillations, the ZCD comparator may not be able to detect

the valleys. To avoid such a situation, the NCL30080 features a time-out circuit that generates pulses if the voltage on ZCD pin stays below the  $V_{ZCD(THD)}$  threshold for 6.5  $\mu s$  (nominal).

The time-out also acts as a substitute clock for the valley detection and simulates a missing valley in case of very damped free oscillations.

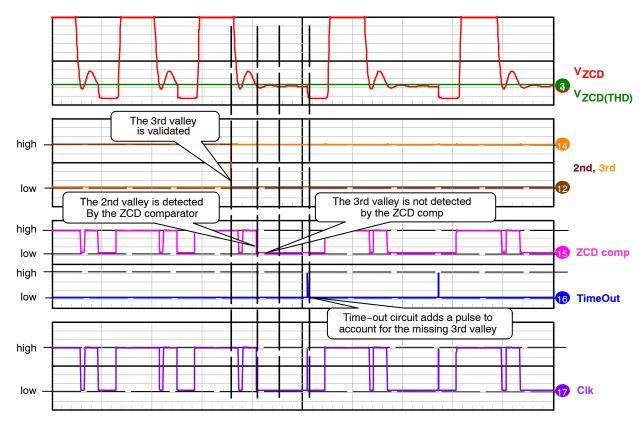


Figure 9. Time-out Chronograms

Normally with this type of time-out function, in the event the ZCD pin or the auxiliary winding is shorted, the controller could continue switching leading to improper regulation of the LED current. Moreover during an output short circuit, the controller will strive to maintain constant current operation.

To avoid these scenarios, a protection circuit consisting of a comparator and secondary timer starts counting when the ZCD voltage is below the  $V_{\rm ZCD(short)}$  threshold. If this timer reaches 90 ms, the controller detects a fault and shutdown. The auto-restart version (B suffix) waits 4 seconds, then the controller restarts switching. In the latched version (A suffix), the controller is latched as long as  $V_{\rm CC}$  stays above the  $V_{\rm CC(reset)}$  threshold.

#### Line Feed-forward

Because of internal and external propagation delays, the MOSFET is not turned-off immediately when the current set-point is reached. As a result, the primary peak current is slightly higher than expected resulting in a small output current error which can be compensated for during component selection.

Normally this error would increase if the input line voltage increased because the slew rate through the primary inductance would increase. To compensate for the peak current increase brought by the variation, a positive voltage proportional to the line voltage is added to the current sense signal. The amount of offset voltage can be adjusted using the R<sub>LFF</sub> resistor as shown in Figure 10.

$$V_{CS(offset)} = K_{LFF}V_{pinVIN}R_{CS}$$
 (eq. 5)

The offset voltage is applied only during the MOSFET on-time.

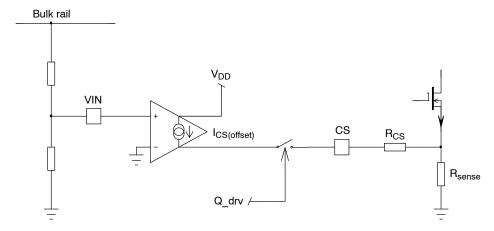
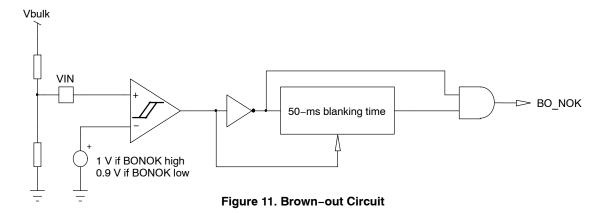


Figure 10. Line Feed-forward Schematic

#### Brown-out

In order to protect the supply against a very low input voltage, the NCL30080 features a brown-out circuit with a fixed ON/OFF threshold. The controller is allowed to start if a voltage higher than 1 V is applied to the VIN pin and shuts-down if the VIN pin voltage decreases and stays below 0.9 V for 50 ms nominal. Exiting a brown-out

condition overrides the hiccup on  $V_{CC}$  ( $V_{CC}$  does not wait to reach  $V_{CC(off)}$ ) and the IC immediately goes into startup mode ( $I_{CC} = I_{CC(start)}$ ). Note for most compact LED driver applications, if a true line dropout occurs, the energy in the input bulk capacitor will be discharged and the LED load will turn off before the 50 ms timer expires.



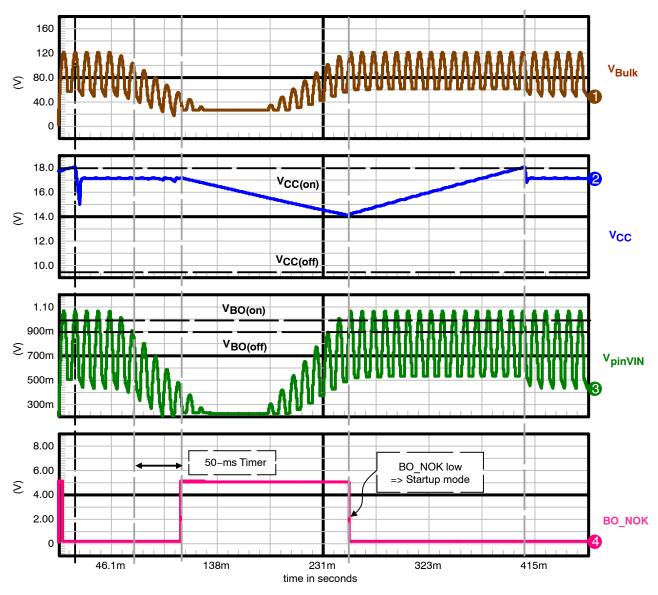


Figure 12. Brown-Out Chronograms (Valley Fill circuit is used)

#### **CS Pin Short Circuit Protection**

With a traditional controller, if the CS pin or the sense resistor is shorted to ground, the driver will not be able to turn off, leading to potential damage of the power supply. To avoid this, the NCL30080 features a circuit to protect the

power supply against a short circuit of the CS pin. When the MOSFET is on, if the CS voltage stays below  $V_{CS(low)}$  after the adaptive blanking timer has elapsed, the controller shuts down and will attempt to restart on the next  $V_{CC}$  hiccup.

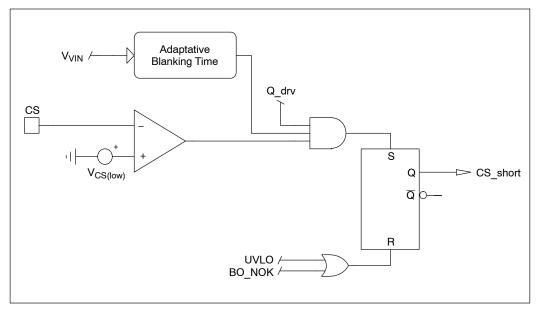


Figure 13. CS Pin Short Circuit Protection Schematic

#### **Fault Management**

#### OFF Mode

The circuit turns off whenever a major condition prevents it from operating:

- Incorrect feeding of the circuit: "UVLO high". The
   UVLO signal becomes high when V<sub>CC</sub> drops below
   V<sub>CC(off)</sub> and remains high until V<sub>CC</sub> exceeds V<sub>CC(on)</sub>.
- V<sub>CC</sub> OVP
- Output diode short circuit protection: "WOD\_SCP high"
- Output / Auxiliary winding Short circuit protection: "Aux SCP high"
- Die over temperature (TSD)
- Brown-Out: "BO NOK" high
- Pin CS short circuited to GND: "CS\_short high"

In this mode, the DRV pulses are stopped. V<sub>CC</sub> voltage decrease through the controller own consumption (I<sub>CC1</sub>).

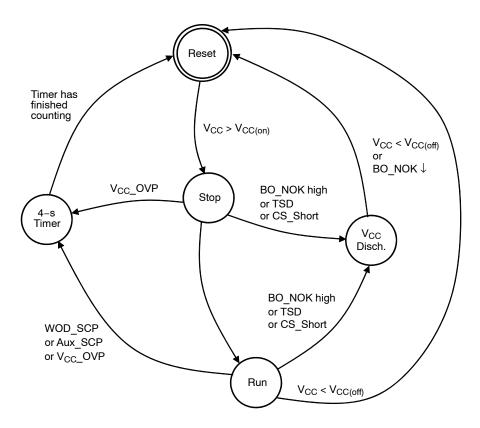
For the output diode short circuit protection, the output / aux. winding short circuit protection and the  $V_{CC}$  OVP, the controller waits 4 seconds (auto-recovery timer) and then initiates a startup sequence  $(V_{CC} \ge V_{CC(on)})$  before re-starting switching.

#### Latch Mode

This mode is activated by the output diode short-circuit protection (WOD\_SCP) and the Aux\_SCP in version A only.

In this mode, the DRV pulses are stopped and the controller is latched. There are hiccups on  $V_{\rm CC}$ .

The circuit un-latches when  $V_{CC} < V_{CC(reset)}$ .



 $\begin{tabular}{lll} \hline With states: Reset & $\rightarrow$ & Controller is reset, $I_{CC} = I_{CC(start)}$ \\ Stop & $\rightarrow$ & Controller is ON, DRV is not switching \\ Run & $\rightarrow$ & Normal switching \\ $V_{CC}$ Disch. & $\rightarrow$ & No switching, $I_{CC} = I_{CC1}$, waiting for $V_{CC}$ to decrease to $V_{CC(off)}$ \\ $4-s$ Timer & $\rightarrow$ & the auto-recovery timer is counting, $V_{CC}$ is ramping up and down between $V_{CC(on)}$ and $V_{CC(off)}$ \\ \hline \end{tabular}$ 

Figure 14. State Diagram for B Version Faults

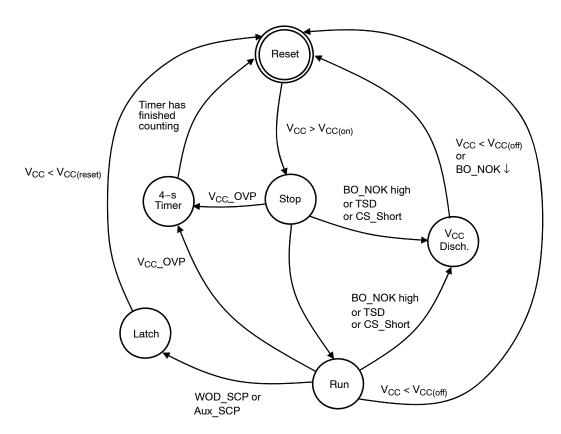
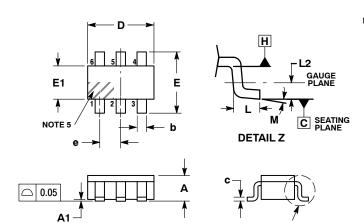


Figure 15. State Diagram for A Version Faults

#### **PACKAGE DIMENSIONS**

#### TSOP-6 CASE 318G-02 ISSUE V

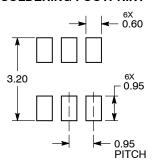


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
  5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

	MILLIMETERS				
DIM	MIN NOM MAX				
Α	0.90	1.00	1.10		
A1	0.01	0.06	0.10		
b	0.25	0.38	0.50		
С	0.10	0.18	0.26		
D	2.90	3.00	3.10		
E	2.50	2.75	3.00		
E1	1.30	1.50	1.70		
е	0.85	0.95	1.05		
L	0.20	0.40	0.60		
L2	0.25 BSC				
M	0°	- 10°			

#### **RECOMMENDED SOLDERING FOOTPRINT\***

DETAIL Z



**DIMENSIONS: MILLIMETERS** 

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **OPTIONS**

Controller	Output SCP	Winding/Output Diode SCP	
NCL30080A	Latched	Latched	
NCL30080B	Auto-recovery	Auto-recovery	

#### **ORDERING INFORMATION**

Device	Package Marking	Package Type	Shipping <sup>†</sup>
NCL30080ASNT1G	AAE	TSOP-6 (Pb-Free, Halide-Free)	3000 / Tape & Reel
NCL30080BSNT1G	AAF	TSOP-6 (Pb-Free, Halide-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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